Re f #	Hits	Search Query	DBs	Defa ult Oper ator	Plu rals	Time Stamp
L1	433	(257/435).CCLS.	US-PG PUB; USPA T; USOC R	OR	OF F	2005/08/ 31 14:01
L2	391	(257/413).CCLS.	US-PG PUB; USPA T; USOC R	OR	OF F	2005/08/ 31 14:16
L3	92	charge adj transfer and electrode and sidewall.clm.	US-PG PUB; USPA T	OR	OF F	2005/08/ 31 14:16
L4	135	charge adj transfer and electrode and sidewall and first near3 layer\$1 and second near2 layer\$1.clm.	US-PG PUB; USPA T	OR	OF F	2005/08/ 31 14:17

L5	135	charge adj transfer and electrode and sidewall and (first near3 layer\$1) and (second near2 layer\$1). clm.	US-PG PUB; USPA T	OR	OF F	2005/08/ 31 14:17
L6	0	charge adj transfer and electrode and sidewall and (first near3 layer\$1) and (second near2 layer\$1) and silicon near2 conductive and common near3 end.clm.	US-PG PUB; USPA T	OR	OF F	2005/08/ 31 14:18
L7	9	charge adj transfer and electrode and sidewall and (first near3 layer\$1) and (second near2 layer\$1) and silicon near2 conductive.clm.	US-PG PUB; USPA T	OR	OF F	2005/08/ 31 14:18